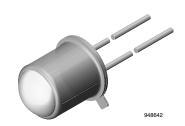


Silicon PIN Photodiode

Description

BPW24R is a high sensitive silicon planar photodiode in a standard TO-18 hermetically sealed metal case with a glass lens.

A precise alignment of the chip gives a good coincidence of mechanical and optical axes. The device features a low capacitance and high speed even at low supply voltages.



Features

- Hermetically sealed TO-18 case
- · Exact central chip alignment
- · Cathode connected to case
- Angle of half sensitivity $\varphi = \pm 12^{\circ}$
- Extra fast response times at low operating voltages
- High photo sensitivity
- Radiant sensitive area A = 0.78 mm²
- Suitable for visible and near infrared radiation
- For photodiode and photovoltaic cell operation
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



Applications

• High speed photo detector



Absolute Maximum Ratings

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse Voltage		V _R	60	V
Power Dissipation	T _{amb} ≤ 25 °C	P _V	210	mW
Junction Temperature		Tj	125	°C
Operating Temperature Range		T _{amb}	- 55 to + 125	°C
Storage Temperature Range		T _{stg}	- 55 to + 125	°C
Soldering Temperature	t ≤ 5 s	T _{sd}	260	°C
Thermal Resistance Junction/ Ambient		R _{thJA}	350	K/W



Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Breakdown Voltage	$I_R = 100 \mu A, E = 0$	V _(BR)	60	200		V
Reverse Dark Current	V _R = 50 V, E = 0	I _{ro}		2	10	nA
Diode capacitance	V _R = 0 V, f = 1 MHz, E = 0	C _D		11		pF
	$V_R = 5 \text{ V, f} = 1 \text{ MHz, E} = 0$	C _D		3.8		pF
	V _R = 20 V, f = 1 MHz, E = 0	C _D		2.5		pF

Optical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Open Circuit Voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	V _o		450		mV
Temp. Coefficient of V _o	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK _{Vo}		- 2		mV/K
Short Circuit Current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	I _k		55		μА
Temp. Coefficient of I _k	E _A = 1 klx	TK _{lk}		0.1		%/K
Reverse Light Current	$E_{e} = 1 \text{ mW/cm}^{2}, \ \lambda = 950 \text{ nm}, \ V_{R} = 20 \text{ V}$	I _{ra}	45	60		μΑ
Absolute Spectral Sensitivity	$V_R = 5 \text{ V}, \lambda = 870 \text{ nm}$	s(λ)		0.60		A/W
	$V_R = 5 \text{ V}, \lambda = 900 \text{ nm}$	s(λ)		0.55		A/W
Angle of Half Sensitivity		φ		± 12		deg
Wavelength of Peak Sensitivity		λ_{p}		900		nm
Range of Spectral Bandwidth		λ _{0.5}		600 to 1050		nm
Rise Time	V_R = 20 V, R_L = 50 Ω , λ = 820 nm	t _r		7		ns
Fall Time	V_R = 20 V, R_L = 50 Ω , λ = 820 nm	t _f		7		ns

Typical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

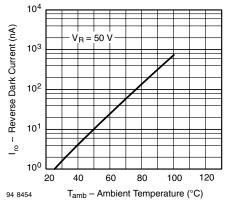


Figure 1. Reverse Dark Current vs. Ambient Temperature

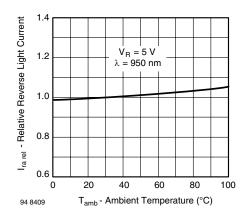


Figure 2. Relative Reverse Light Current vs. Ambient Temperature



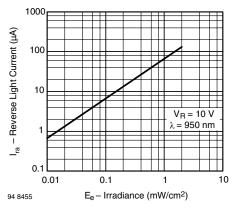


Figure 3. Reverse Light Current vs. Irradiance

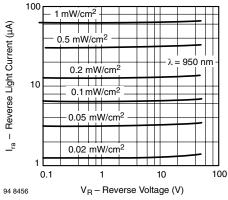


Figure 4. Reverse Light Current vs. Reverse Voltage

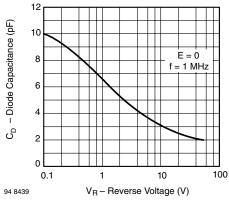


Figure 5. Diode Capacitance vs. Reverse Voltage

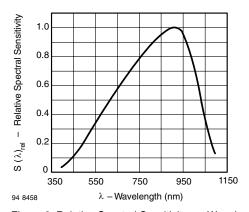


Figure 6. Relative Spectral Sensitivity vs. Wavelength

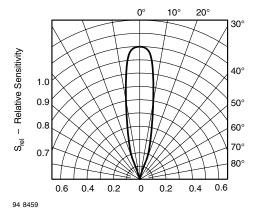
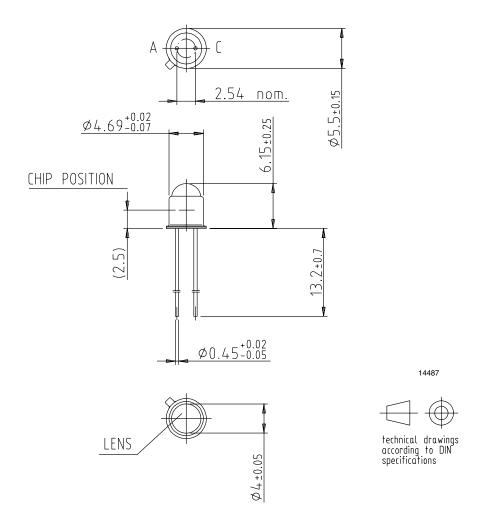


Figure 7. Relative Radiant Sensitivity vs. Angular Displacement

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Package Dimensions in mm





Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

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